Systematic convergence for realistic projects

Fast versus accurate

Daniel Sánchez-Portal

Centro de Física de Materiales, Centro Mixto CSIC-UPV/EHU,San Sebastián, Spain

Email: sqbsapod@sc.ehu.es

Thanks to José M. Soler and A. García

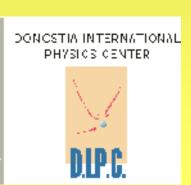
Efficient density-functional calculations with atomic orbtitals: a hands-on tutorial on the SIESTA code

CECAM Tutorial

Lyon, June 18-22







Basic strategy

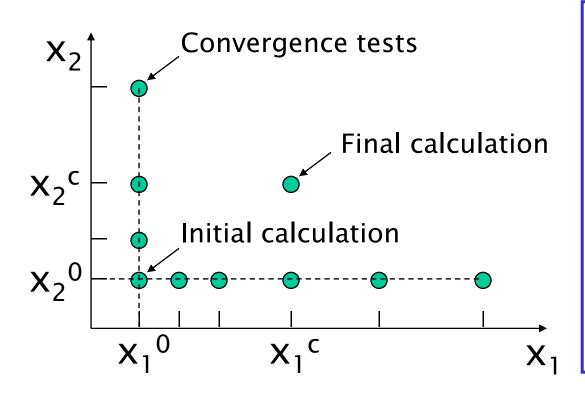
Steps of a typical research project:

- 1. Exploratory-feasibility tests
- 2. Convergence tests
- 3. Converged calculations

A fully converged calculation is impossible without convergence tests

Convergence tests

- Choose relevant magnitude(s) A of the problem (e.g. an energy barrier or a magnetic moment)
- Choose set of qualitative and quantitative parameters x_i (e.g. xc functional, number of k-points, etc)



Goal: Approx. parameter independence:

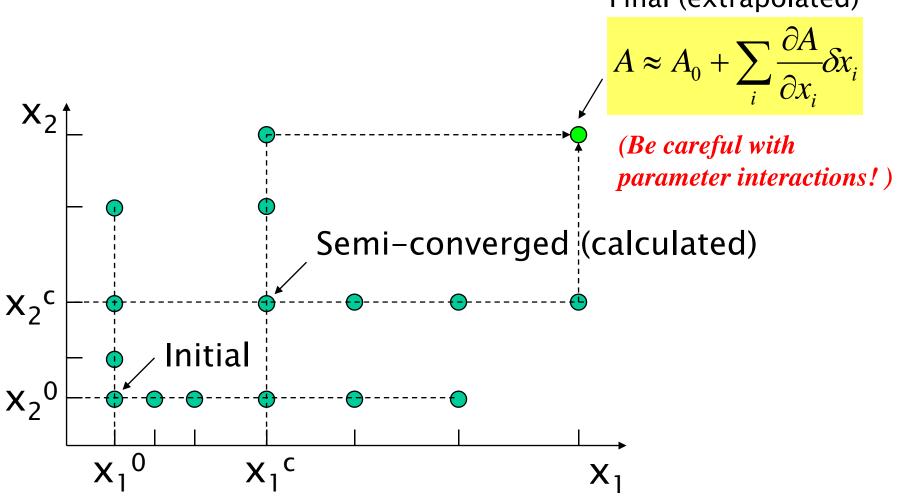
$$\frac{\partial A}{\partial x_i}$$
 < our tolerance

Monitor:

- Convergence
- CPU time & memory

Multi-stage convergence

Final (extrapolated)



Practical hints

- •Ask your objective: find the truth or publish a paper?
- •Do not try a converged calculation from the start
- •Start with minimum values of all x_i
- •Do not assume convergence for any x_i
- Choose a simpler reference system for some tests
- Take advantage of error cancellations
- •Refrain from stopping tests when results are "good"

What determines the accuracy of your calculation?

- -Variational freedom and adequacy of your basis set
- -Accuracy of your pseudopotentials and appropriate definition of the "active" (valence) electrons
- -DFT and used XC-functional
- -Fineness of your k-sampling (specially for metals)
- -Electronic temperature: not always such a good friend!
- -Fineness of the real-space grid (SIESTA)

More complete parameter list

- Pseudopotential
 - Method of generation
 - Number of valence states
 - Number of angular momenta
 - Core radii
 - Nonlinear core corrections
- Number of k-points
- Electronic temperature
- •XC functional: LDA, GGAs
- Harris functional vs SCF
- Spin polarization
- SCF convergence tolerance
- Supercell size (solid & vacuum)
- Geometry relaxation tolerance
 - Check of final stability

- Basis set
 - Number of functions
 - · Highest angular momentum
 - Number of zetas
 - Range
 - Shape
 - Sankey
 - Optimized
- ·Real space mesh cutoff
 - Grid-cell sampling
- Neglect nonoverlap interactions
- •O(N) minimization tolerance

Parameter interactions

$$\partial^2 A / \partial x_i \partial x_j \neq 0$$

Number of k-points:

- •Supercell size
- •Geometry
- •Electronic temperature
- Spin polarization
- •Harris vs SCF

Mesh cutoff:

- Pseudopotential
- •Nonlinear core corrections
- Basis set
- •GGA

Why basis sets of atomic orbitals?

Good things about LCAO:

- -Physically motivated: very few functions can do a good job!
- -Localized:

short-range interactions = sparse matrices

linear scaling algorithms become possible

more intuitive "chemistry" captured

Are atomic orbitals appropriate?

Bad things about LCAO:

- -Lack of systematic convergence (as opposite to PW or grids)
- -Link to the atoms:

some states (very delocalized) might be difficult to represent easy to guess for occupied states but, what about excitations? basis changes with atomic positions (BSSE)

Improving the quality of the basis set

Single- ζ (minimal or SZ)

One single radial function per angular

momentum shell occupied in the free -atom



Radial flexibilization:

Add **more than one** radial function within the same angular momentum than SZ

Multiple-ζ

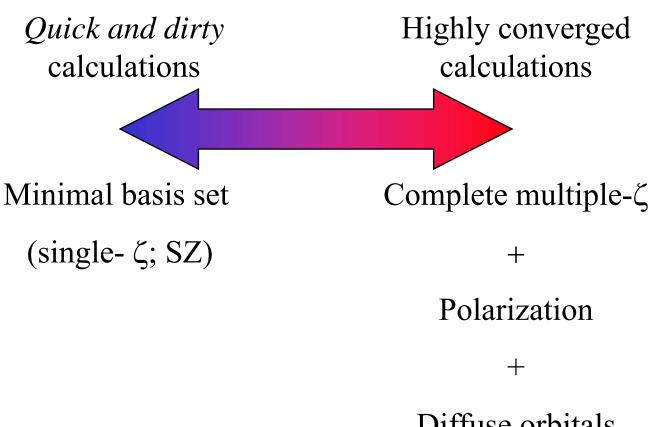
Angular flexibilization:

Add shells of different atomic symmetry (different l)

Polarization

Size

Depending on the required accuracy and available computational power



Diffuse orbitals

HOW BAD ARE THE RESULTS WITH A SZ BASIS?

Bad!, but... not so bad as you might expect:

- -bond lengths are too large
- -energetics changes considerably, however, energy differences might be reasonable enough
- -charge transfer and other basic chemistry is usually OK (at least in simple systems)
- -if the geometry is set to the experiment, we typically have a nice band structure for occupied and lowest unoccupied bands

When SZ basis set can be used:

- -long molecular dynamics simulations (once we have make ourselves sure that energetics is reasonable)
- -exploring very large systems and/or systems with many degrees of freedom (complicated energy landscape).

Examples

Atom	Valence	SZ		DZ		P		
	configuration							
		# orbital	s symmetry	# orbita	ls symmetry	# orbitals	symmetry	
Si	$3s^2 \ 3p^2$	1	s	2	s	1	d_{xy}	
		1	p_x	2	p_x	1	d_{yz}	
		1	p_y	2	p_y	1	$egin{array}{c} d_{zx} \ d_{x^2-y^2} \ d_{3z^2-r^2} \end{array}$	
		1	p_z	2	p_z	1	$d_{x^2-y^2}$	
						1	$d_{3z^2-r^2}$	
	Total	4		8		(DZ+P) 13		

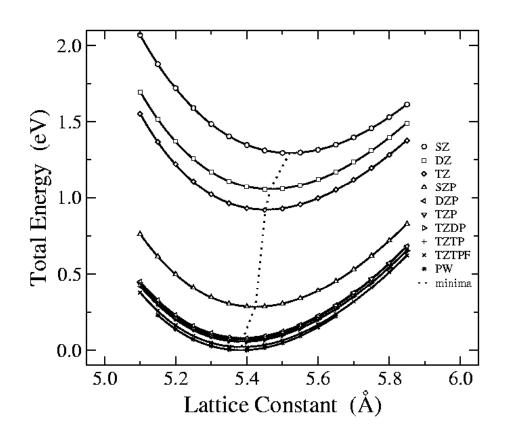
Atom	Valence						
	configuration						
		# orbital	s symmetry	# orbitals	symmetry	# orbitals	symmetry
Fe	$4s^2 \ 3d^6$	1	s	2	s	1	p_x
		1	d_{xy}	2	d_{xy}	1	p_y
		1	d_{yz}	2	d_{yz}	1	p_z
		1	d_{zx}	2	d_{zx}		
		1	$d_{x^2-y^2} \ d_{3z^2-r^2}$	2	$egin{array}{c} d_{zx} \ d_{x^2-y^2} \ d_{3z^2-r^2} \end{array}$		
		1	$d_{3z^2-r^2}$	2	$d_{3z^2-r^2}$		
	Total	6		12		(DZ+P) 15	1

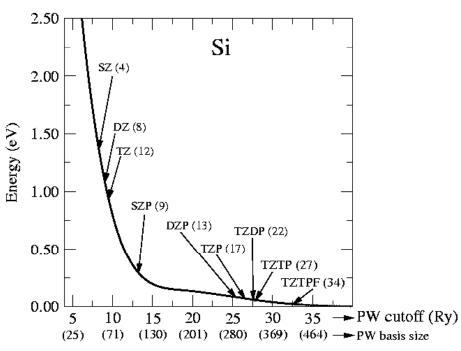
Convergence of the basis set

Bulk Si

Cohesion curves

PW and NAO convergence





Equivalent PW cutoff (E_{cut}) to optimal DZP

System	DZP # funct.	PW # funct.	E _{cut} (Ry)
	per atom	per atom	
H_2	5	11296	34
O_2	13	45442	86
Si	13	227	22
diamond	13	284	59
α-quartz	13	923	76

For molecules: cubic unit cell 10 Å of side

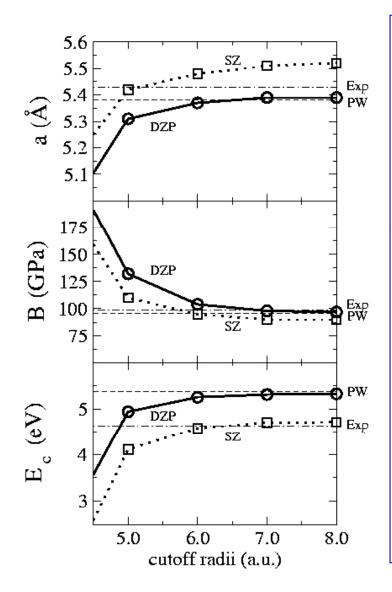
Range

- How to get sparse matrix for O(N)
 - Neglecting interactions below a tolerance or beyond some scope of neighbours ⇒ numerical instablilities for high tolerances.
 - Strictly localized atomic orbitals (zero beyond a given cutoff radius, r_c)



- •Accuracy and computational efficiency depend on the range of the atomic orbitals
 - •Way to define all the cutoff radii in a balanced way

Convergence with the range



bulk Si

equal s, p

orbitals radii

Remarks:

- -Not easy to get
- -Longer not better if basis set is not complet enough
- -Affects cohesion, but energy differences converge better
- -More relevant for surfaces, small molecules and/or adsorbates (BSSE)

J. Soler et al, J. Phys: Condens. Matter, 14, 2745 (2002)

Energy shift

$$\left(-\frac{1}{2r}\frac{d^2}{dr^2}r + \frac{l(l+1)}{2r^2} + V_l(r)\right)\phi_l(r) = (\epsilon_l + \delta\epsilon_l)\phi_l(r)$$

A single parameter for all cutoff radii

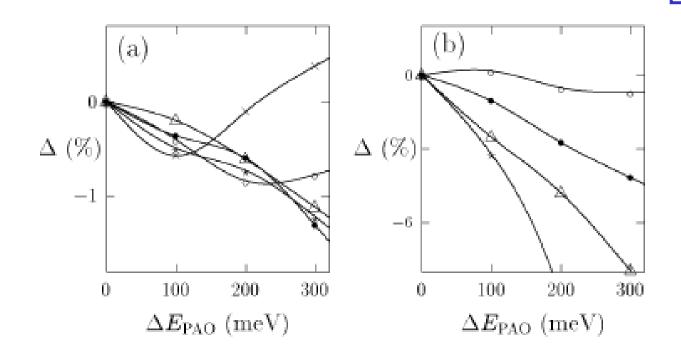
E. Artacho et al. *Phys. Stat. Solidi* (b) 215, 809 (1999)

Convergence vs Energy shift of

Bond lengths Bond energies

Reasonable values for practical calculations:

 $\Delta E_{\rm PAO} \sim 50-200 \; {\rm meV}$



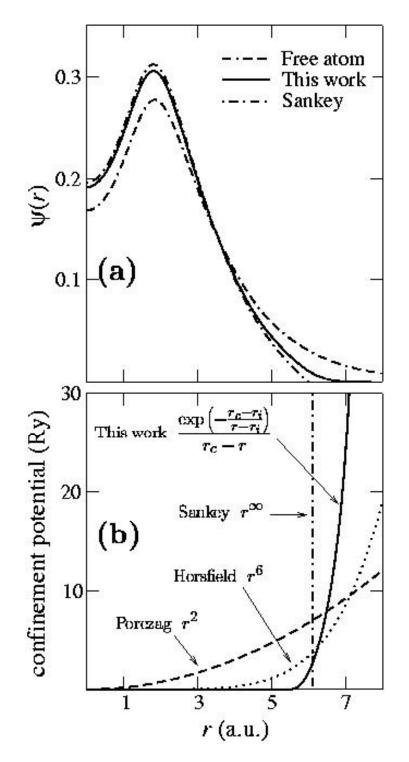
Soft confinement

(J. Junquera *et al*, Phys. Rev. B **64**, 235111 (01))

3s of Mg in MgO for different confinement schemes

Optimized confinement potential:

- Better variational basis sets
- •Removes the discontinuity of the derivative
- Coming soon to the official version



Procedure

Difference in energies involved in your problem?

•SZ: (Energy shift)

Semiquantitative results and general trends

•DZP: automatically generated (Split Valence and Peturbative polarization)

High quality for most of the systems.

Good valence: well converged results ↔computational cost

'Standard'

Rule of thumb in Quantum Chemistry:

A basis should always be doubled before being polarized

Convergence of the basis set

Bulk Si

	SZ	DZ	TZ	SZP	DZP	TZP	TZDP	PW	APW	Exp
a (Å)	5.52	5.46	5.45	5.42	5.39	5.39	5.39	5.38	5.41	5.43
B (GPa)	89	96	98	98	97	97	96	96	96	98.8
E _c (eV)	4.72	4.84	4.91	5.23	5.33	5.34	5.34	5.37	5.28	4.63

 $SZ = single-\zeta$

P=Polarized

PW: Converged Plane Waves (50 Ry)

 $DZ = doble - \zeta$

DP=Doble-polarized

APW: Augmented Plane Waves

TZ=triple- ζ

(all electron)

System		Exp	LAPW	PW	PW	DZP
				(Literature)	(same ps)	
	a	4.08	4.05	4.07	4.05	4.07
Au	В	173	198	190	191	188
	E_c	3.81	-	-	4.19	4.03
	a	3.57	3.54	3.54	3.53	3.54
C	В	442	470	436	466	453
	E_c	7.37	10.13	8.96	8.90	8.81
	a	4.23	4.05	3.98	3.95	3.98
Na	В	6.9	9.2	8.7	8.8	9.2
	E_c	1.11	1.44	1.28	1.22	1.22
	a	3.60	3.52	3.56	-	3.57
Cu	В	138	192	172	-	165
	E_{c}	3.50	4.29	4.24	-	4.37

a (Å) B(GPa) $E_c(eV)$

Real-space grid: Mesh cut-off

Different from PW calculations, used to project $\rho(\mathbf{r})$ in order to calculate:

- -XC potential (non linear function of $\rho(\mathbf{r})$)
- -Solve Poisson equation to get Hartree potential
- -Calculate three center integrals (difficult to tabulate and store)

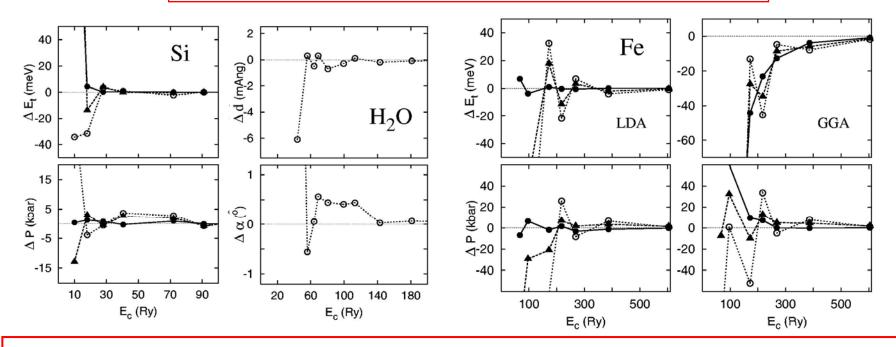
$$<\phi_i(\mathbf{r}-\mathbf{R}_i) \mid V_{local}(\mathbf{r}-\mathbf{R}_k) \mid \phi_j(\mathbf{r}-\mathbf{R}_j)>$$

-IMPORTANT this grid is NOT part of the basis set...

is an AUXILIAR grid and, therefore, convergence of energy is not necessarily variational respect to its fineness.

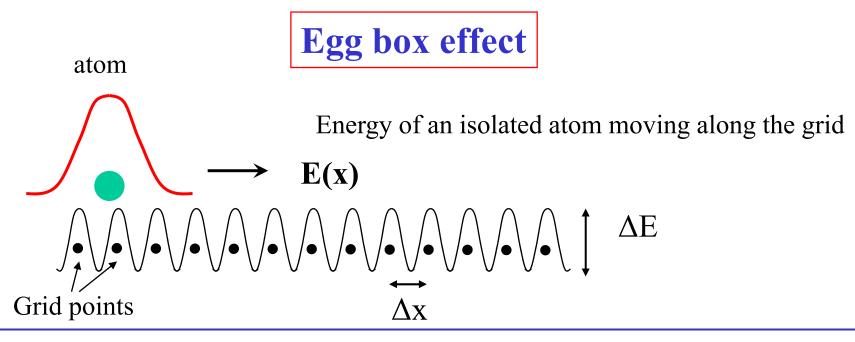
-Mesh cut-off: highest energy of PW that can be represented with such grid.

Convergence of energy with the grid



Important tips:

- -Never go below 100 Ry unless you know what you are doing.
- -Values between 150 and 200 Ry provide good results in most cases
- -GGA and pseudo-core require larger values than other systems
- -To obtain very fine results use **GridCellSampling**
- -Filtering of orbitals and potentials coming soon (Eduardo Anglada)

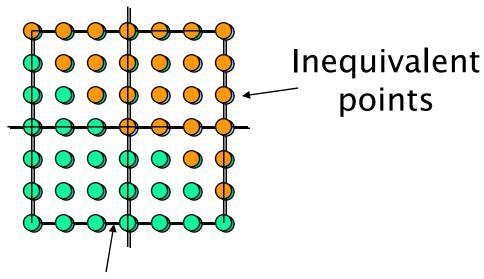


We know that ΔE goes to zero as Δx goes to zero, but what about the ratio $\Delta E/\Delta x$?:

- Tipically **covergence of forces is somewhat slowler** than for the total energy
- This has to be taken into account for very precise relaxations and phonon calculations.
- Also important and related: tolerance in forces should not be smaller than tipical errors in the evaluation of forces.

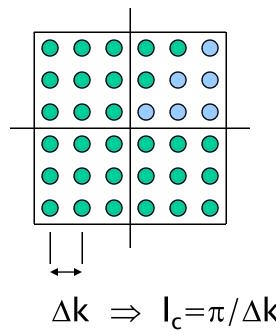
K-point sampling

Only time reversal (k=-k)symRegyulaedkin sjirista



First Brillouin Zone

Monkhorst-Pack

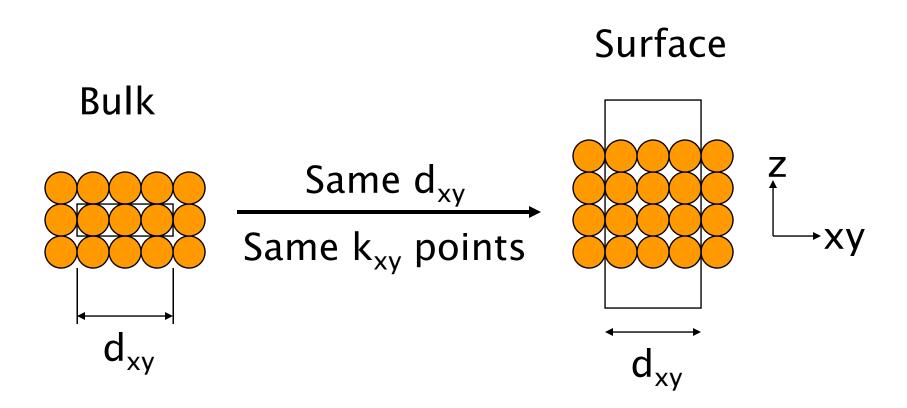


$$\Delta k \Rightarrow I_c = \pi/\Delta k$$

k-sampling

- -Only time reversal symmetry used in SIESTA (k=-k)
- -Convergence in SIESTA not different from other codes:
 - •Metals require a lot of k-point for perfect convergence (explore the Diag.ParallelOverK parallel option)
 - •Insulators require much less k-points
- -Gamma-only calculations should be reserved to really large simulation cells
- -As usual, an incremental procedure might be the most intelligent approach:
 - •Density matrix and geometry calculated with a "reasonable" number of k-points should be close to the converged answer.
 - •Might provide an excellent input for more refined calculations

Surface (slab) calculations



Convergence of the density matrix

DM.MixingWeight:
$$ho_{in}^{n+1} = \alpha
ho_{out}^n + (1-\alpha)
ho_{in}^n$$

 α is not easy to guess, has to be small at most 0.1-0.15 for insulator and semiconductors, tipically much smaller for metals

DM.NumberPulay (DM.NumberBroyden): N

$$\bar{\rho}_{in}^{n} = \sum_{i=1}^{N} \beta_{i} \rho_{in}^{(n-N+i)}$$

$$\bar{\rho}_{out}^{n} = \sum_{i=1}^{N} \beta_{i} \rho_{out}^{(n-N+i)}$$

$$\bar{\rho}_{out}^{n} = \alpha \bar{\rho}_{out}^{n} + (1 - \alpha) \bar{\rho}_{in}^{n}$$
such that $|\bar{\rho}_{in}^{n} - \bar{\rho}_{out}^{n}|$
is minimum
$$\bar{\rho}_{out}^{n} = \sum_{i=1}^{N} \beta_{i} \rho_{out}^{(n-N+i)}$$
N between 3 and 7 usually gives the best results

$$\rho_{in}^{n+1} = \alpha \bar{\rho}_{out}^n + (1 - \alpha) \bar{\rho}_{in}^n$$

gives the best results

Convergence of the density matrix

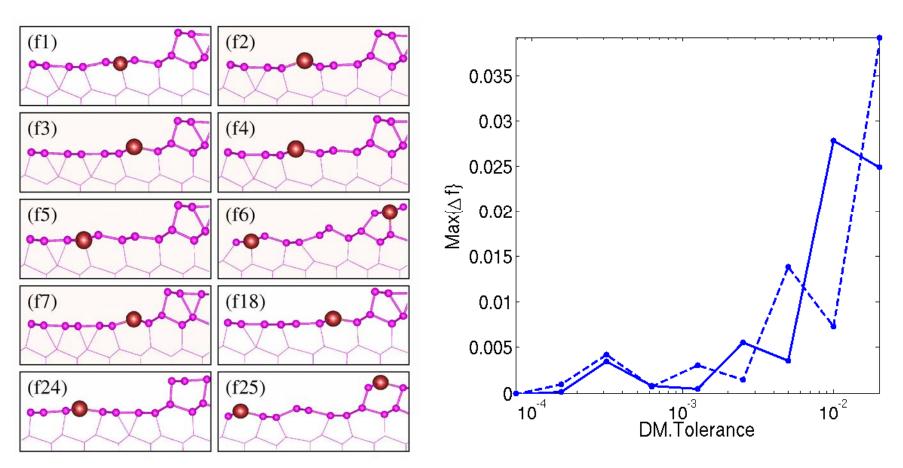
DM.Tolerance: you should stick to the default 10⁻⁴ or use even smaller values unless.....

- ...you know what you are doing:
- -Preliminary relaxations
- -Systems that resist complete convergence but your are *almost* there
- -in particular if the Harris energy is very well converged
- -NEVER go above 10⁻³
- -ALWAYS CHECK THAT THINGS MAKE SENSE.

A particular case where DM. Tolerance could be reduced

Determination of the Si(553)/Au structure

More than 200 structures explored



S. Riikonen and DSP

Harris functional

$$\rho(\mathbf{r}) = \sum_{i} |\psi_{i}(\mathbf{r})|^{2}$$

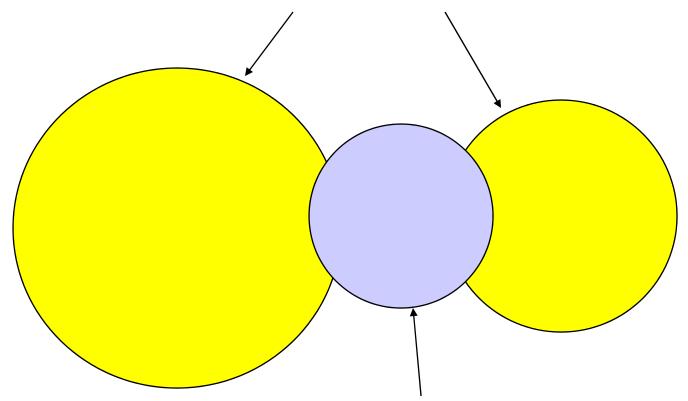
$$\begin{split} \mathsf{E}_{\mathsf{KS}}\left[\rho\right] &= -(1/2) \; \Sigma_{\mathsf{i}} \big| \nabla \psi_{\mathsf{i}}(\mathsf{r}) \big|^2 + \int \mathsf{V}_{\mathsf{ext}}(\mathsf{r}) \; \rho(\mathsf{r}) \; \mathsf{d}\mathsf{r} \\ &+ (1/2) \; \int \mathsf{V}_{\mathsf{H}}(\mathsf{r}) \; \rho(\mathsf{r}) \; \mathsf{d}\mathsf{r} \; + \; \int \epsilon_{\mathsf{xc}}(\mathsf{r}) \; \rho(\mathsf{r}) \; \mathsf{d}\mathsf{r} \end{split}$$

$$E_{Harris} [\rho_{in}] = E_{KS} [\rho_{in}] + Tr[(\rho_{out} - \rho_{in})H_{in}]$$

- Much faster SCF convergence
- ·Usually $\rho_{in} = \sum \rho_{atoms}$ and no SCF

Neglect of non-overlap interactions

Basis orbitals



KB pseudopotential projector

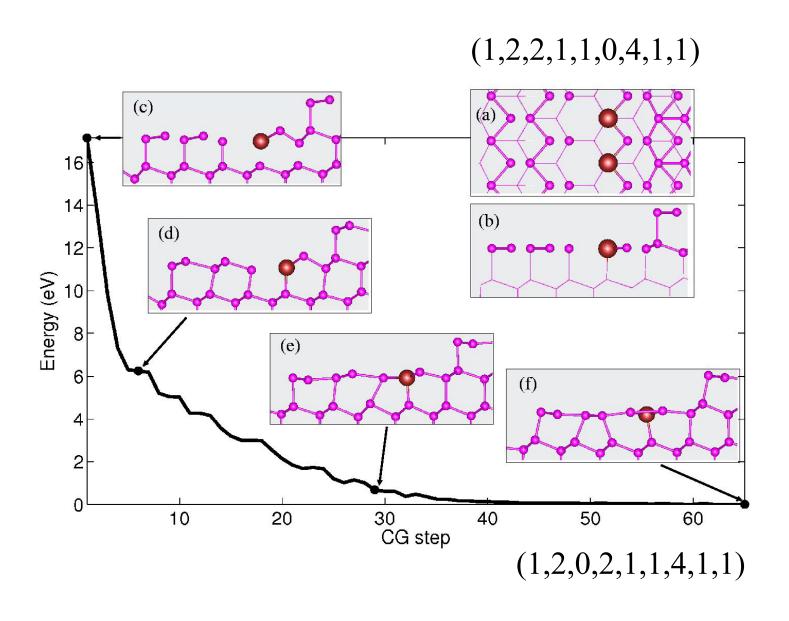
Incremental approach to convergence

i) SZ basis set, 2x1 sampling, constraint relaxations, slab with two silicon bulayers, DM.Tol=10⁻³ only surface layer: first relax interlayer height, then relaxations with some constraints to preserve model topology.

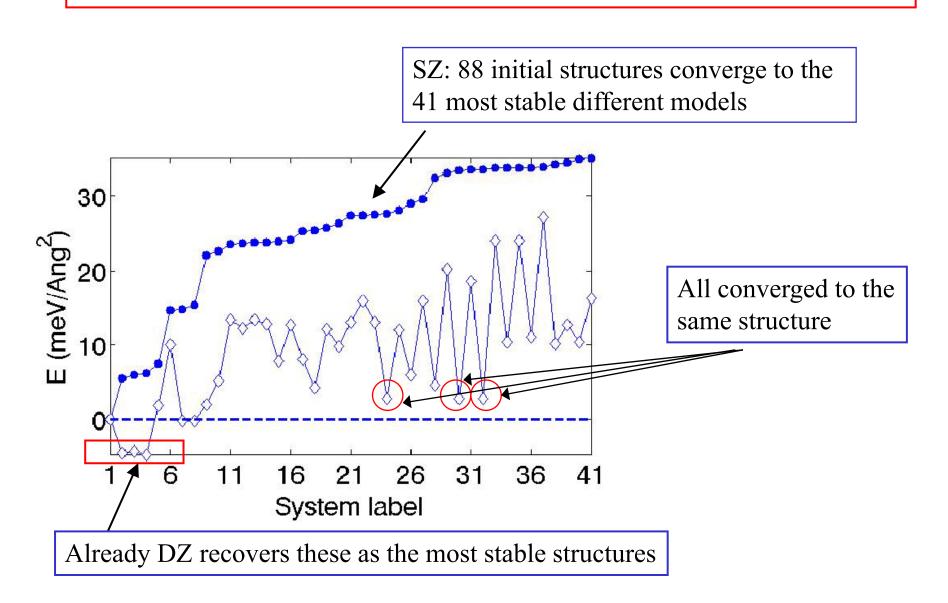
Selecting a subset with the most stable models

- ii) DZ basis set, 8x4 sampling, full relaxation, slab with four silicon bilayers, DM.Tol=10⁻³ Rescaling to match DZ bulk lattice parameter
- iii) DZ basis set, 8x4 sampling, full relaxation, DM.Tol=10⁻⁴
- iv) DZP basis set, 8x4 sampling, full relaxation, DM.Tol=10⁻⁴ Rescaling to match DZ bulk lattice parameter

Automatic guess + first constraint relaxations with SZ



SZ energies might be a guide to select reasonable candidates, but... caution is needed!!!!



Finally we get quite accurate answer....

Name	$\Delta E (meV/Å^2)$				
	SIESTA	VASP			
p2*	4.85	4.93			
p4* p5*	6.44	6.54			
p5*	9.51	9.13			
f1	4.63	4.27			
f2	0.17	-0.08			
f4	0.00	0.00			

